



HS1A THRU HS1M

1.0 AMP. High Efficient Surface Mount Rectifiers



Voltage Range
50 to 1000 Volts
Current
1.0 Ampere

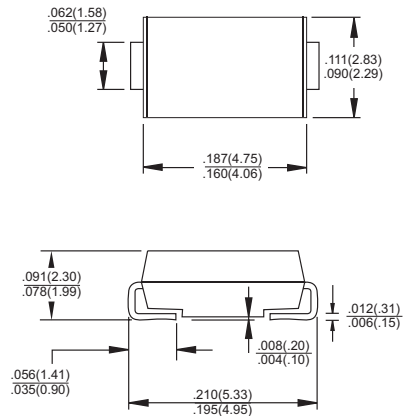
Features

- ✧ Glass passivated junction chip.
- ✧ For surface mounted application
- ✧ Low forward voltage drop
- ✧ Low profile package
- ✧ Built-in stain relief, ideal for automatic placement
- ✧ Fast switching for high efficiency
- ✧ High temperature soldering:
260°C/10 seconds at terminals
- ✧ Plastic material used carries Underwriters
Laboratory Classification 94V-0

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Terminals: Solder plated
- ✧ Polarity: Indicated by cathode band
- ✧ Packing: 12mm tape per E1A STD RS-481
- ✧ Weight: 0.064 gram

SMA/DO-214AC



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	HS 1A	HS 1B	HS 1D	HS 1F	HS 1G	HS 1J	HS 1K	HS 1M	Units	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current See Fig.2	$I_{(AV)}$	1.0								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30								A	
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.0			1.3		1.7			V	
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=100^\circ\text{C}$	I_R					5.0		100			μA μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	50				75				nS	
Typical Junction Capacitance (Note 2)	C_j	20				15				pF	
Maximum Thermal Resistance (Note 3)	$R_{\theta JA}$	70								$^\circ\text{C/W}$	
Operating Temperature Range	T_J	-55 to +150								$^\circ\text{C}$	
Storage Temperature Range	T_{STG}	-55 to +150								$^\circ\text{C}$	

- Notes: 1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
 2. Measured at 1 MHz and Applied $V_R=4.0$ Volts
 3. Mounted on P.C.B. with 0.2"x0.2" (5 x 5 mm) Copper Pad Areas.

RATINGS AND CHARACTERISTIC CURVES (HS1A THRU HS1M)

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

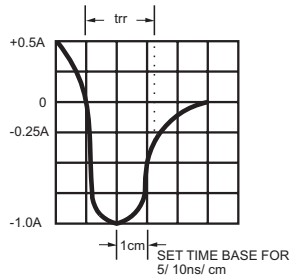
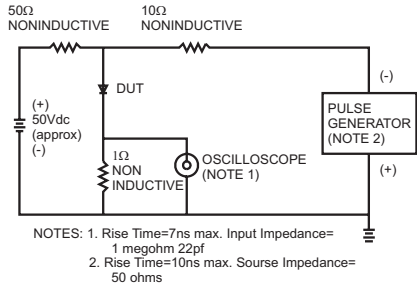


FIG.2- MAXIMUM AVERAGE FORWARD CURRENT DERATING

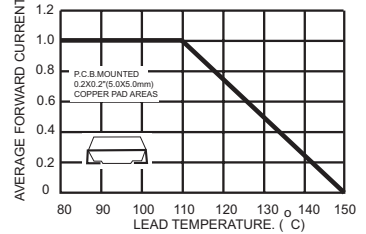


FIG.3- TYPICAL REVERSE CHARACTERISTICS

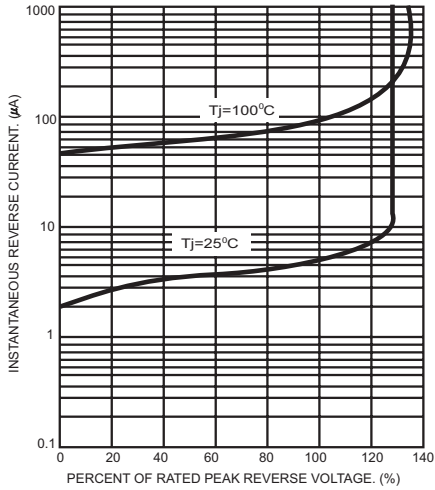


FIG.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

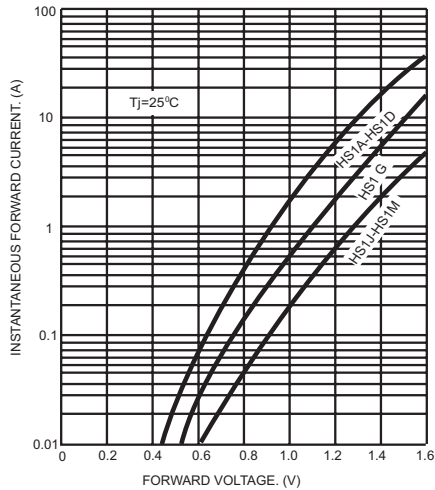


FIG.5- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

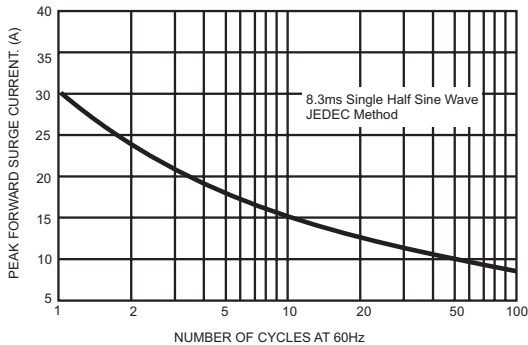


FIG.6- TYPICAL JUNCTION CAPACITANCE

